




2N108-1N184


TYPE	MATERIAL	POLARITY	REPLACE- MENT	PAGE NUMBER	USE	MAXIMUM RATINGS							ELECTRICAL CHARACTERISTICS							
						P _D @ 25°C	T _J Ref Point °C	V _{CB} (volts)	V _{CE} (volts)	Subscript	h _{FE} @ I _C (min) (max)	V _{CE(SAT)} @ I _C (volts)	h _f Subscript	f _t Units	Subscript					
2N108 2N109 2N110 2N111 2N111A 2N112 2N112A 2N113 2N114 2N115 2N117 2N118	G G G G G G G G G G S	P P P P P P P P P P N	2N1192	6-30	AFA AFC MSS RFA RFA RFA RFA RFA RFA PMS HSA HSA	50M 165M 0.2W 150M 150M 150M 150M 96M 96M 50W 150M 150M	A A A A A A A A A C C C	71 85 30 30 30 30 10 32 30 150 150	35 50 30 15 30 15 10 10 32 30 30	25 0 0 0 0	65 115 15 15 15 15	50M 1.0M 1.0M 1.0M 1.0M	0.15 2.5 50M 18M	50	E					
2N118A 2N119 2N120 2N122 2N123 2N124 2N125 2N126 2N127 2N128 2N129 2N130	S S S S S G G G G G G G	N N N N P N N N N P P P			HSA HSA RFA LPA HSA MSS MSS MSS MSS RFA RFA AFA	150M 150M 150M 8.75W 50M 50M 50M 50M 50M 30M 30M 85M	C C C C J A A A A A A A	150 150 175 150 85 75 75 75 75 85 85 85	45 30 45 120 20 10 10 10 10 10 4.5 4.5	15 0	3.0 7.6 333	100M 5.0M 5.0M 5.0M 5.0M 5.0M	0.3 5.0M 0.3 5.0M 0.3 5.0M	0.9 0.95 0.974 0.987	B B B B	1.0M 2.0M	B B			
2N130A 2N131 2N131A 2N132 2N132A 2N133 2N133A 2N135 2N136 2N137 2N138 2N138A	G G G G G G G G G G G G	P P P P P P P P P P P P	2N650 2N1192 2N651 2N1192 2N651 2N1192 2N651	6-20 6-30 6-20 6-30 6-20 6-30 6-20	AFA AFA AFA AFA AFA LMA RFA RFA RFA AFA AFA AFA	100M 85M 100M 85M 100M 100M 100M 100M 100M 100M 50M 150M	A A A A A A A A A A A A	85 85 85 24 35 30 85 35 20 12 12 6.0 24 45	40 30 30 20 20 0 0 0 0	0 0 0 0 0 0 0 0 0	10 50M	50M		14 27	E E					
2N138B 2N139 2N140 2N141 2N142 2N143 2N144 2N145 2N146 2N147 2N148 2N148A	G G G G G G G G G G G G	P P P P P P P N N N N N			AFA AFC AFC LPA LPA LPA LPA RFA RFA RFA RFA RFA	100M 80M 80M 1.5W 1.5W 1.0W 1.0W 65M 65M 65M 65M 65M	A A A A A A A A A A A A	85 70 16 25 25 25 60 75 75 75 75	45 16 16 60 60 30 30 30 20 20 20 16 32	U U U U U U U										
2N149 2N149A 2N150 2N150A 2N155 2N156 2N157 2N157A 2N158 2N158A 2N159 2N160	G G G G G G G G G G S	N N N N P P P P P P N	2N176 2N176 2N1531 2N1532 2N2139 2N2141	7-20 7-20 7-60 7-60 7-78 7-78	RFA RFA RFA RFA LPA LPA LPA LPA LPA LPA AFA	65M 65M 65M 65M 1.5W 1.5W 1.5W 1.5W 1.5W 1.5W 0.15W	A A A A A A A A A A A	75 75 75 75 85 85 85 85 85 80 40	16 32 16 32	U U U U		0.65 0.6 0.5A 1.0A 0.75 0.75	0.5A 0.5A 1.0A	145K 100K 100K 145K 4.0K	B B B B E					
2N160A 2N161 2N161A 2N162 2N162A 2N163 2N163A 2N166 2N167 2N167A 2N169 2N168A	S S S S S S S G G G G G	N N N N N N N N N N N N			AFA AFA AFA AFA AFA AFA AFA RFC HSA HSA RFC RFC	0.15W 0.15W 0.15W 0.15W 0.15W 0.15W 0.15W 25M 75M 75M 55M 65M	A A A A A A A A A A A A A	40 40 40 40 40 40 40 50 85 30 30 15 15	40 40 40 40 40 40 40 6.0 30 30 15 15	0 0 0 0 0 0	9.0 19 19 19 19 39 39	19 39 39 199 199 199	8.0M	0.952 0.952 20 20	B B E E	5.0M 5.0M	B B			
2N169 2N169A 2N170 2N172 2N173 2N174 2N174A 2N175 2N176 2N178 2N179 2N180 2N181 2N182 2N183 2N184	G G G G G G G G G G G G G G G G	N N N N N P P P P P P P N N N N	2N1192 2N176 2N1192	6-30 7-25 7-17 6-30 7-20 7-22 7-20 6-30 6-30	RFC AFC RFC RFA RFA PMS PMS AFC AFC AFA AFA MSS MSS MSS	65M 65M 25M 65M 65M 10W 100W 100W 50M 90W 40W 0.15W 0.25W 0.1W 0.1W 0.1W	A A A A A C C C C C C A A A A A	85 85 50 75 75 95 95 80 80 70 10 40 75 75 25 25 25	15 25 6.0 30 30 60 70 70 40 30 30 30 30 30 30	0 0 0 0 0 0 0 0	35 70 25 40 25 45	70 50 80 80	5.0A 5.0A 1.2A	1.0 0.9 0.7	12A 12A 12A	100K	B E E			


GERMANIUM POWER TRANSISTOR SELECTOR GUIDE (continued)


10 - AMP P ₀ = 85 W f _r = 0.7 MHz *P ₀ = 56 W *f _r = 1.0 MHz	HIGH-VOLTAGE LOW-SATURATION SWITCH 	h_{FE} $I_C = 3 A,$ $V_{CE} = 2 V$	V_{CEO} V_{CE}	80 V	120 V	160 V	V_{CES}	
				80 V	120 V	160 V	200 V	320 V
		20-50 20 min *		2N2526	2N2527	2N2528	MP3730*	MP3731*


15 - AMP P ₀ = 170 W f _r = 0.3 MHz	GENERAL PURPOSE SWITCH AND AMPLIFIER 	h_{FE} $I_C = 5 A,$ $V_{CE} = 2 V$	V_{CES} V_{CE}	40 V	50 V	70 V	80 V	
				40 V	50 V	70 V	80 V	
		20-40		2N2078	2N2077	2N2076	2N2075	
35-70		2N2082	2N2081	2N2080	2N2079			

15 - AMP P ₀ = 150 W f _r = 0.3 MHz	GENERAL PURPOSE SWITCH AND AMPLIFIER 	h_{FE} $I_C = 5 A,$ $V_{CE} = 2 V$	V_{CES} V_{CE}	40 V	45 V	50 V	70 V	80 V
				40 V	50 V	60 V	80 V	100 V
		20-40		2N441	2N442	2N443		
25-50					2N174	2N1100		
35-70		2N277	2N278	2N173	2N1099			

15 - AMP P ₀ = 106 W	HIGH-FREQUENCY SWITCH AND AMPLIFIER 	h_{FE} $I_C = 10 A,$ $V_{CE} = 2 V$	V_{CES} V_{CE}	30 V	45 V	60 V	75 V	
				40 V	60 V	80 V	100 V	
		10-30 f _r = 0.55 MHz		2N1549	2N1550	2N1551	2N1552	
30-60 f _r = 0.4 MHz		2N1553	2N1554	2N1555	2N1556			
50-100 f _r = 0.4 MHz		2N1557	2N1558	2N1559	2N1560			

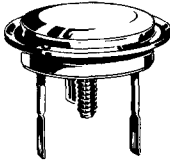
20 - AMP P ₀ = 85 W f _r = 18 MHz	HIGH-SPEED SWITCH 	h_{FE} $I_C = 10 A,$ $V_{CE} = 2 V$	V_{CEO} V_{CE}	50 V		75 V		100 V
				80 V		120 V		140 V
		25-100		2N2832		2N2833		2N2834

25 - AMP P ₀ = 106 W f _r = 0.4 MHz	HIGH DC GAIN SWITCH 	h_{FE} $I_C = 25 A,$ $V_{CE} = 1 V$	V_{CES} V_{CE}	35 V		60 V		75 V
				50 V		80 V		100 V
		15-65		2N1162		2N1164		2N1166
		2N1163†		2N1165†		2N1167†		

25 - AMP P ₀ = 75 W f _r = 10 MHz	HIGH DC GAIN LOW-SATURATION SWITCH 	h_{FE} $I_C = 5 A,$ $V_{CE} = 2 V$	$V_{CE(sat)}$ $I_C = 25 A,$ $I_E = 2.5 A$ V_{CE}	0.5 V				
				15 V				
		200-800				2N2912		

2N277 (GERMANIUM)
2N278
2N173
2N1099

$V_{CB} = 40-80V$
 $I_E = 15A$
 $P_D = 170W$



CASE 5
(TO-36)

PNP germanium power transistors for general purpose power amplifier and switching applications. Power and temperature ratings exceed EIA registration.

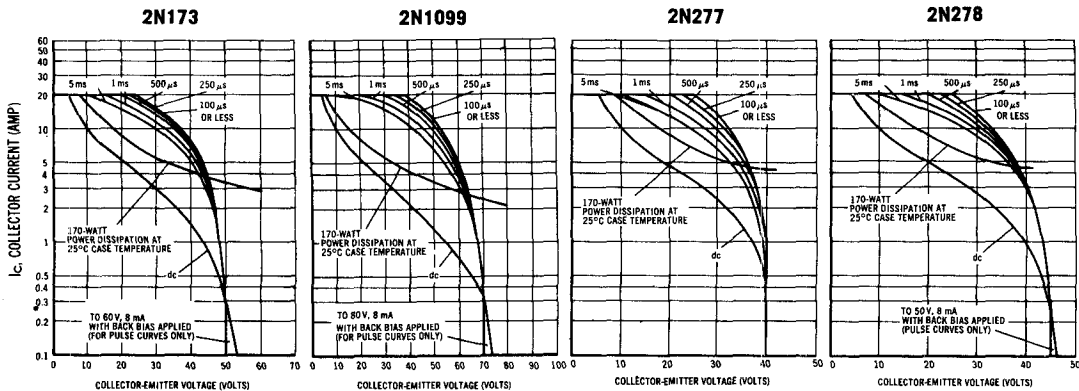
MAXIMUM RATINGS

Rating	Symbol	2N277	2N278	2N173	2N1099	Unit
Collector-Base Voltage	V_{CB}	40	50	60	80	Vdc
Emitter-Base Voltage	V_{EB}	20	30	40	40	Vdc
Emitter Current-Continuous	I_E	15				A _{dc}
Base Current	I_B	4				A _{dc}
Total Device Dissipation @ $T_C = 25^\circ C$ Derate above $25^\circ C$	P_D	170			2	Watts W/ $^\circ C$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +110				$^\circ C$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	0.5	$^\circ C/W$

SAFE OPERATING AREAS



The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector-emitter short.

(Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J , the power-temperature derating curve must be observed for both steady state and pulse power conditions.

2N277, 2N278, 2N173, 2N1099 (continued)

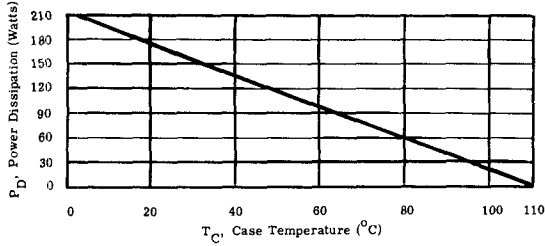
ELECTRICAL CHARACTERISTICS (At 25°C unless otherwise noted)

Characteristic		Symbol	Minimum	Typical	Maximum	Unit
Collector-Base Cutoff Current $V_{CB0} = 2 \text{ V}$		I_{CB0}	—	100	—	μA
Collector-Base Cutoff Current $V_{EB} = 1.5 \text{ V}, V_{CB} = 40 \text{ V}$	2N277 50 60 80	I_{CB}	— — — —	2 2 2 2	8 8 8 8	mA
Emitter-Base Cutoff Current $V_{EBO} = 20 \text{ V}$	2N277 2N278 2N173 2N1099	I_{EBO}	— — — —	1 1 1 1	8 8 8 8	mA
Collector-Base Cutoff Current $V_{CB0} = 40 \text{ V}, 71^\circ\text{C}$	2N277 2N278 2N173 2N1099	I_{CB0}	— — — —	— — — —	15 15 15 15	mA
Collector-Emitter Voltage $I_C = 300 \text{ mA}, V_{EB} = 0$	2N277 2N278 2N173 2N1099	BV_{CES}^*	40 45 50 70	— — — —	— — — —	Vdc
Collector-Emitter Voltage $I_C = 1 \text{ Amp}, I_B = 0$	2N277 2N278 2N173 2N1099	BV_{CEO}^*	25 30 45 55	— — — —	— — — —	Vdc
Floating Potential $I_E = 0, V_{CB} = 40 \text{ V}$	2N277 2N278 2N173 2N1099	V_{fl}	— — — —	0.15 0.15 0.15 0.15	1.0 1.0 1.0 1.0	volt
Current Gain $I_C = 5 \text{ Amp}, V_{CB} = 2 \text{ V}$ $I_C = 12 \text{ Amp}, V_{CB} = 2 \text{ V}$		h_{FE}	35 —	— 25	70 —	—
Base-Emitter Voltage $I_C = 5 \text{ Amp}, V_{CB} = 2 \text{ V}$	2N277 2N278 2N173 2N1099	V_{BE}	— — — —	0.65 0.65 0.65 0.65	— — — 0.9	Vdc
Saturation Voltage $I_C = 12 \text{ Amp}, I_B = 2 \text{ Amp}$	2N277 2N278 2N173 2N1099	$V_{CE(SAT)}$	— — — —	0.3 0.3 0.3 0.3	— 1.0 1.0 0.7	Vdc
Common-Emitter Current Amplification Cutoff Frequency $I_C = 5 \text{ Amp}, V_{CE} = 6 \text{ V}$		$f_{\alpha e}$	0.3	10	—	kHz
Rise Time "on" $I_C = 12 \text{ Adc},$ $I_B = 2 \text{ Adc}, V_{CE} = 12 \text{ V}$		t_r	—	15	—	μs
Fall Time "off" $I_C = 0,$ $V_{EB} = 6 \text{ V}, R_{EB} = 10 \text{ Ohms}$		t_f	—	15	—	μs

* To avoid excessive heating of the collector junction, perform these tests with the sweep method.

2N277, 2N278, 2N173, 2N1099 (continued)

POWER-TEMPERATURE DERATING CURVE

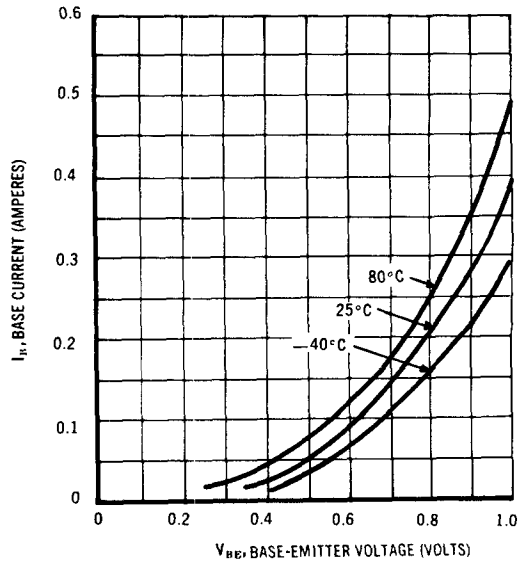


The maximum continuous power is related to maximum junction temperature by the thermal resistance factor.

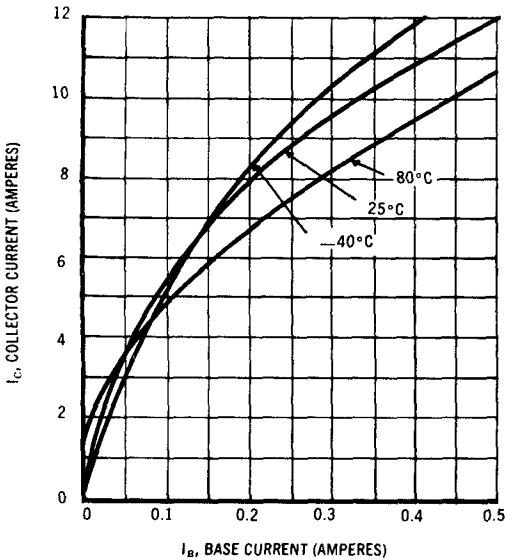
This curve has a value of 150 Watts at case temperatures of 25°C and is 0 Watts at 110°C with a linear relation between the two temperatures such that:

$$\text{allowable } P_D = \frac{110^\circ - T_C}{0.5}$$

INPUT CHARACTERISTICS



CURRENT TRANSFER CHARACTERISTICS



TRANSCONDUCTANCE CHARACTERISTICS

